



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

CPH6350 — P-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- 4V drive
- Low ON-resistance
- Protection diode in

Specifications

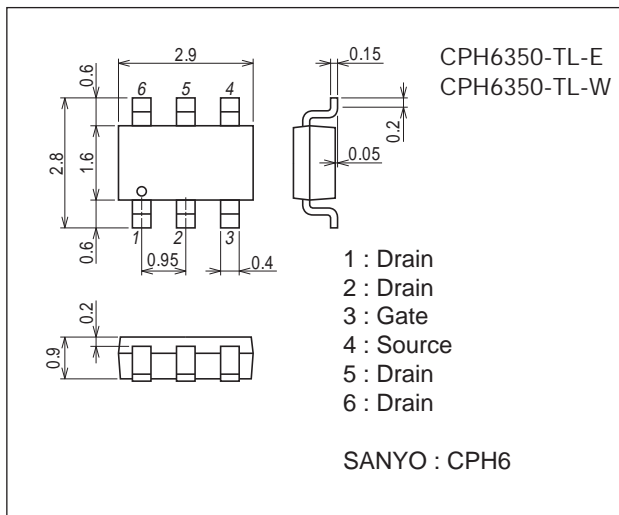
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-30	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-6	A
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-24	A
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ)

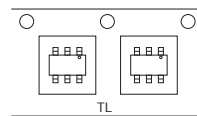
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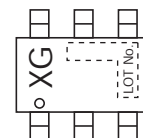
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

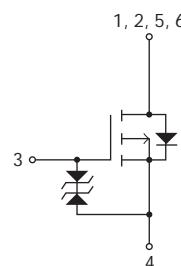
Packing Type: TL



Marking



Electrical Connection

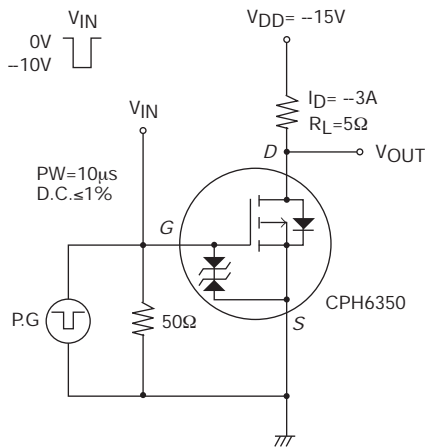


CPH6350

Electrical Characteristics at Ta=25°C

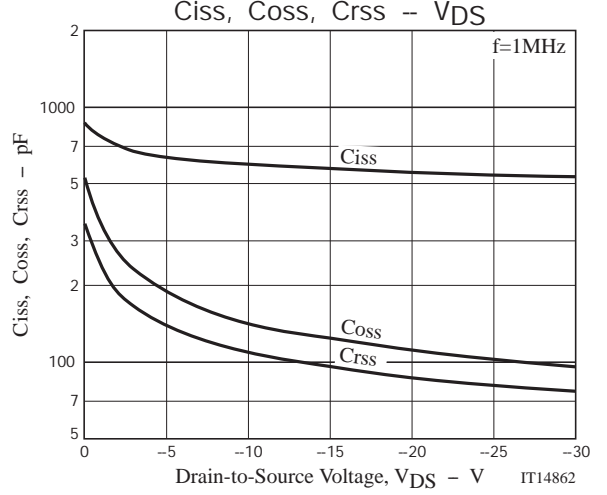
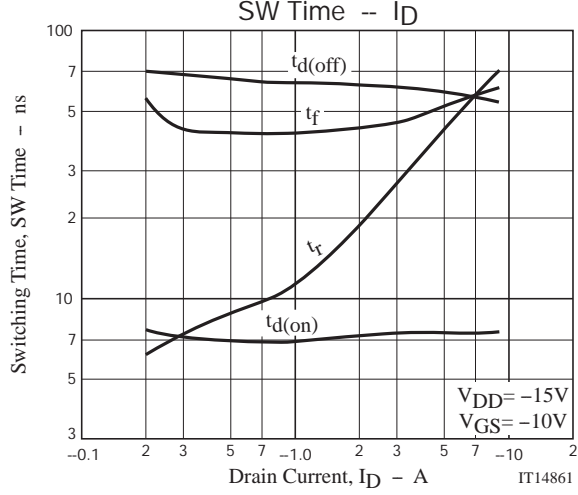
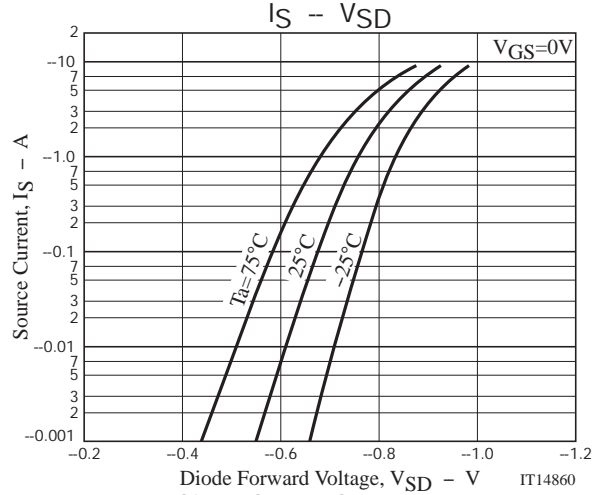
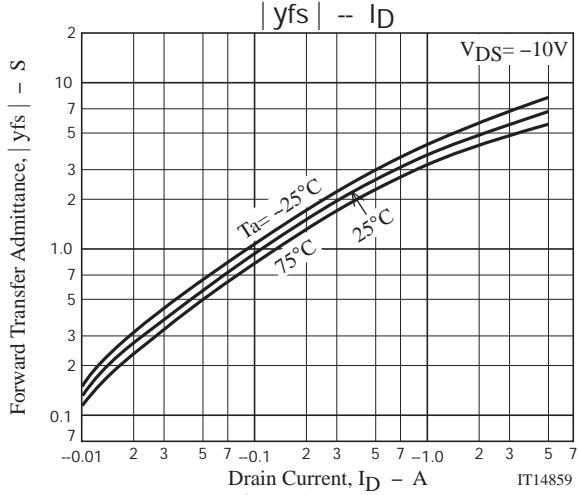
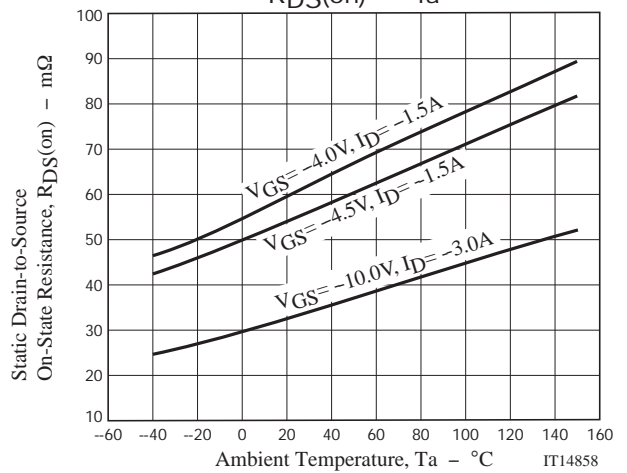
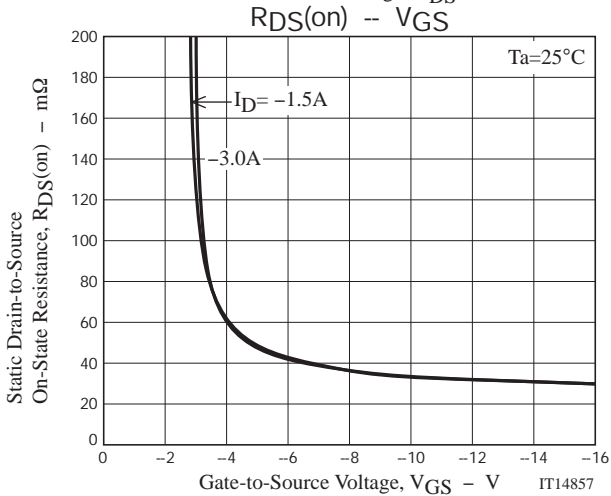
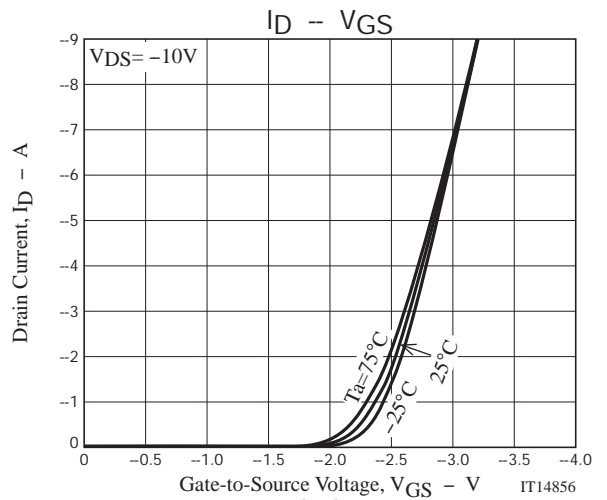
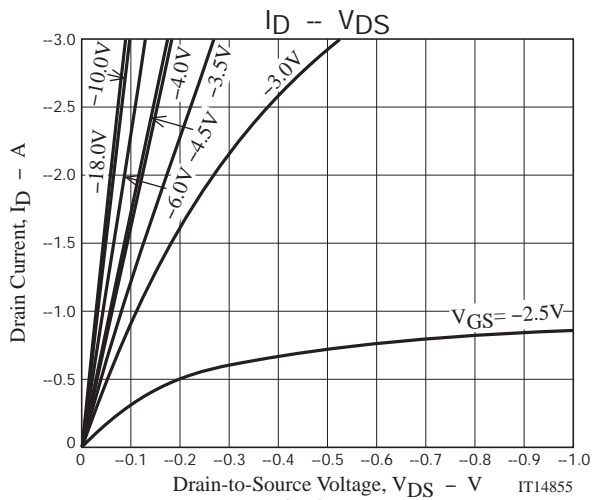
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _{GS} =0V	-30			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-3A		5.4		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-3A, V _{GS} =-10V		33	43	mΩ
	R _{DS(on)2}	I _D =-1.5A, V _{GS} =-4.5V		58	82	mΩ
	R _{DS(on)3}	I _D =-1.5A, V _{GS} =-4V		61	86	mΩ
Input Capacitance	C _{iss}	V _{DS} =-10V, f=1MHz		600		pF
Output Capacitance	C _{oss}			145		pF
Reverse Transfer Capacitance	C _{rss}			110		pF
Turn-ON Delay Time	t _{d(on)}		See specified Test Circuit.		7.4	
Rise Time	t _r			27		ns
Turn-OFF Delay Time	t _{d(off)}			62		ns
Fall Time	t _f			45		ns
Total Gate Charge	Q _g	V _{DS} =-15V, V _{GS} =-10V, I _D =-6A			13	
Gate-to-Source Charge	Q _{gs}			1.8		nC
Gate-to-Drain "Miller" Charge	Q _{gd}			3.2		nC
Diode Forward Voltage	V _{SD}	I _S =-6A, V _{GS} =0V		-0.87	-1.2	V

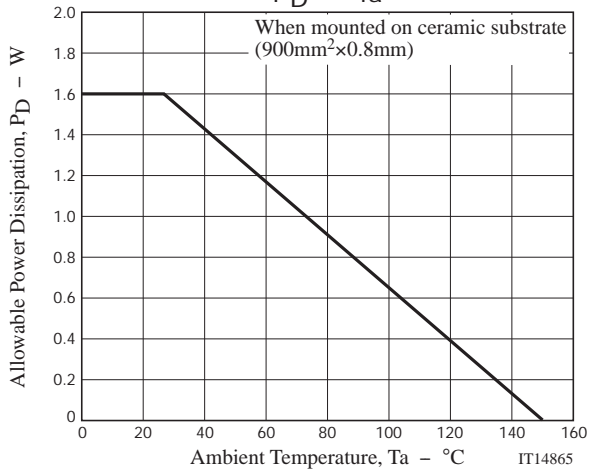
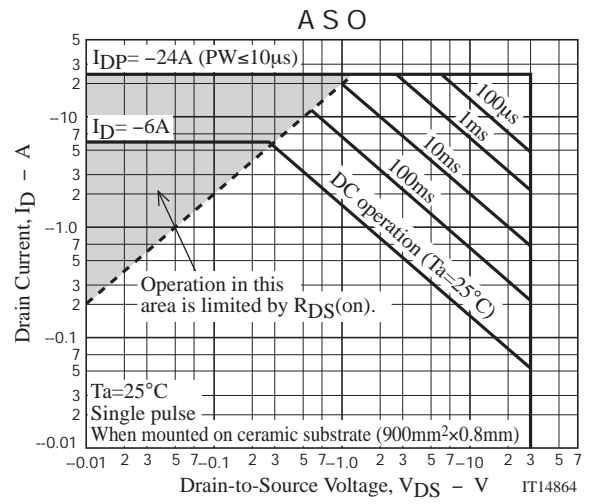
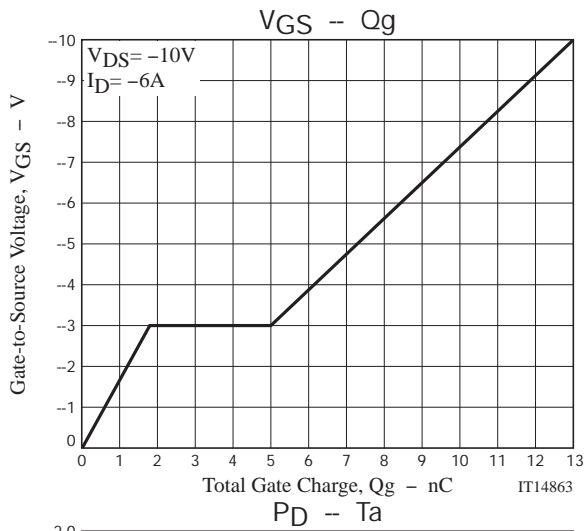
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
CPH6350-TL-E	CPH6	3,000pcs./reel	Pb Free
CPH6350-TL-W	CPH6	3,000pcs./reel	Pb Free and Halogen Free





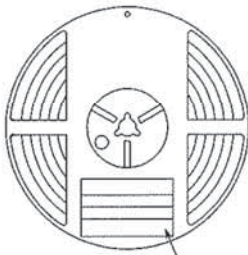
CPH6350

Embossed Taping Specification CPH6350-TL-E, CPH6350-TL-W

1. Packing Format

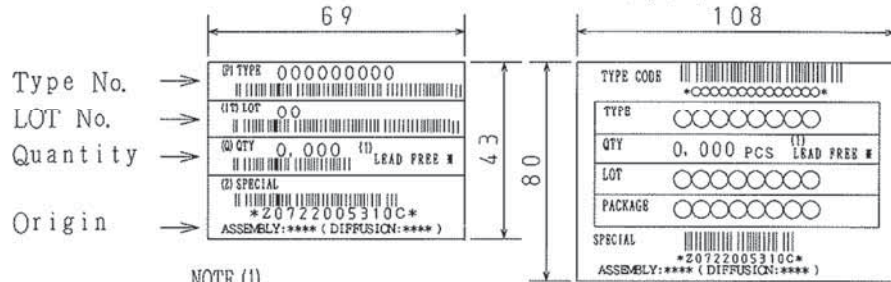
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH6	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label

Reel label, Inner box label (unit:mm) Outer box label
It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



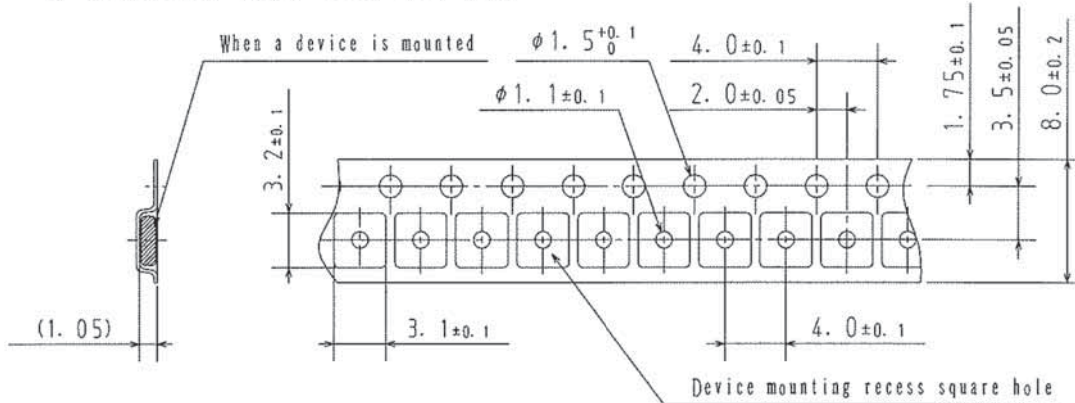
NOTE (1)

The LEAD FREE # description shows that the surface treatment of the terminal is lead free.

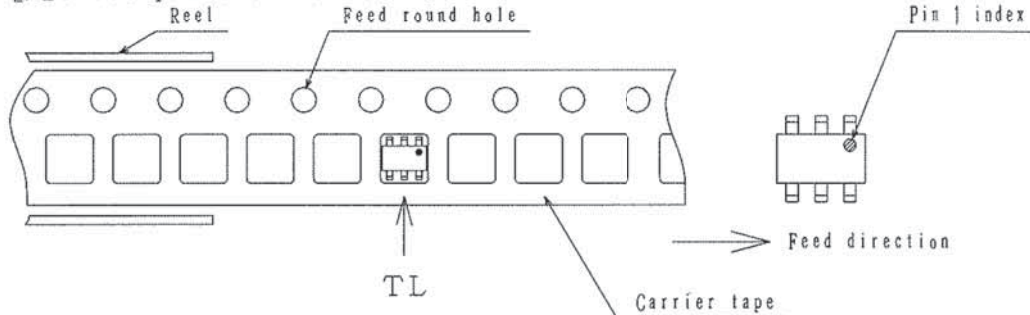
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



Those with pin 1 index on the feed hole side.....TL

Note on usage : Since the CPH6350 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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